

Octal Bus Buffer/Line Driver

Inverting with 3-State Outputs

MC74VHC240, MC74VHCT240A

The MC74VHC240/MC74VHCT240A is a high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. The device achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The MC74VHC240/MC74VHCT240A is an inverting 3-state buffers with two active-low output enables. The device is designed to drive bus lines or buffer memory address registers.

The MC74VHC240 inputs are compatible with standard CMOS levels while the MC74VHCT240A inputs are compatible with TTL levels. The MC74VHCT240A can be used as a level converter for interfacing 3.3 V to 5.0 V, because it has full 5.0 V CMOS level output swings.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The MC74VHC240 and MC74VHCT240A input structures tolerate voltages up to 5.5 V, allowing the interface of 5 V systems to 3 V systems.

The MC74VHCT240A output structures provide protection when $V_{\rm CC}$ = 0 V. These output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

Features

- High Speed: $t_{PD} = 3.8 \text{ ns (Typ)}$ at $V_{CC} = 5.0 \text{ V (VHC)}$ $t_{PD} = 5.6 \text{ ns (Typ)}$ at $V_{CC} = 5.0 \text{ V (VHCT)}$
- Low Power Dissipation: $I_{CC} = 4.0 \mu A$ (Max) at $T_A = 25^{\circ}C$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\%$
- Power Down Protection Provided
- Balanced Propagation Delays
- Designed for: 2.0 V to 5.5 V (VHC)

4.5 V to 5.5 V (VHCT)

• Low Noise: $V_{OLP} = 0.9 \text{ V (Max) (VHC)}$

 $V_{OLP} = 1.1 \text{ V (Max) (VHCT)}$

- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 100 mA
- ESD Performance: Human Body Model > 2000 V;
- Chip Complexity: 120 FETs or 30 Equivalent Gates
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

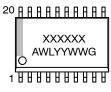


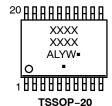
SOIC-20 DW SUFFIX CASE 751D



TSSOP-20 DT SUFFIX CASE 948E

MARKING DIAGRAMS





SOIC-20

A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT

OEA [1●	20] v _{cc}
A1 [2	19	OEB
YB4	3	18	YA1
A2 [4	17] B4
YB3	5	16	YA2
A3 [6	15] B3
YB2	7	14] <u>YA3</u>
A4 [8	13] B2
YB1	9	12	YA4
GND [10	11] B1
			•

FUNCTION TABLE

INPL	JTS	OUTPUTS
OEA, OEB	A, B	₹A, ₹B
L L H	L H X	H L Z

ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

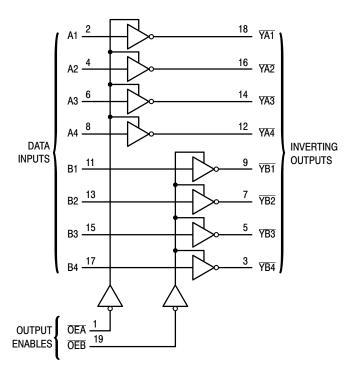


Figure 1. Logic Diagram

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		-0.5 to +6.5	V
V _{IN}	DC Input Voltage		-0.5 to +6.5	V
V _{OUT}	DC Output Voltage (MC74VHC)		-0.5 to V _{CC} + 0.5	V
	Tristat	gh or Low State) e Mode (Note 1) ode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +6.5 -0.5 to +6.5	
I _{IN}	DC Input Current, per Pin		±20	mA
I _{OUT}	DC Output Current, Per Pin		±25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins		±75	mA
I _{IK}	Input Clamp Current		-20	mA
lok	Output Clamp Current	MC74VHC240 IC74VHCT240A	±20 –20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$ heta_{\sf JA}$	Thermal Resistance (Note 2)	SOIC-20W TSSOP-20	96 150	°C/W
P _D	Power Dissipation in Still Air at 25°C	SOIC-20W TSSOP-20	1302 833	mW
MSL	Moisture Sensitivity All	SOIC-20W Other Packages	Level 3 Level 1	-
F _R	Flammability Rating Oxyger	n Index: 28 to 34	UL 94 V-0 @ 0.240 in	-
V _{ESD}	9 ()	man Body Model ed Device Model	2000 N/A	V
I _{LATCHUP}	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

^{1.} Applicable to devices with outputs that may be tri-stated.

Applicable to devices with outputs that may be the stated.
 Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
MC74VHC					•
V _{CC}	DC Supply Voltage		2.0	5.5	V
V _{IN}	DC Input Voltage (Note 5)		0	5.5	V
V _{OUT}	DC Output Voltage (Note 5)		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 3.0 V to 3.6 V V _{CC} = 4.5 V to 5.5 V	0 0	100 20	ns/V
MC74VHC	т			•	•
V _{CC}	DC Supply Voltage		4.5	5.5	V
V _{IN}	DC Input Voltage (Note 5)		0	5.5	V
V _{OUT}		lode (High or Low State) Tristate Mode r-Off Mode (V _{CC} = 0 V)	0 0 0	V _{CC} 5.5 5.5	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 4.5 V to 5.5 V	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

5. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (MC74VHC240)

			V _{CC}		T _A = 25°C	;	T _A = - 40) to 85°C	
Symbol	Parameter	Test Conditions	v	Min	Тур	Max	Min	Max	Unit
V _{IH}	Minimum High-Level Input Voltage		2.0 3.0 to 5.5	1.50 V _{CC} x 0.7			1.50 V _{CC} x 0.7		V
V _{IL}	Maximum Low-Level Input Voltage		2.0 3.0 to 5.5			0.50 V _{CC} x 0.3		0.50 V _{CC} x 0.3	V
V _{OH}	Minimum High-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		
V _{OL}	Maximum Low-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu A$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44	
l _{in}	Maximum Input Leak- age Current	V _{in} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μА
I _{OZ}	Maximum Three-State Leakage Current	$V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$	5.5			±0.25		±2.5	μΑ
I _{CC}	Maximum Quiescent Supply Current	V _{in} = V _{CC} or GND	5.5			4.0		40.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (MC74VHC240)

				T _A = 25°C		$T_A = -40$) to 85°C	
Symbol	Parameter	Test Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Maximum Propagation Delay, A to YA or B to YB	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $C_L = 15 \text{ pF}$ $C_L = 50 \text{ pF}$		5.3 7.8	7.5 11.0	1.0 1.0	9.0 12.5	ns
		$V_{CC} = 5.0 \pm 0.5 \text{ V}$ $C_L = 15 \text{ pF}$ $C_L = 50 \text{ pF}$		3.6 5.1	5.5 7.5	1.0 1.0	6.5 8.5	
t _{PZL} , t _{PZH}	Output Enable Time OEA to YA or OEB to YB	$V_{CC} = 3.3 \pm 0.3 \ V C_L = 15 \ pF \\ C_L = 50 \ pF$		6.6 9.1	10.6 14.1	1.0 1.0	12.5 16.0	ns
		$V_{CC} = 5.0 \pm 0.5 \text{ V}$ $C_L = 15 \text{ pF}$ $C_L = 50 \text{ pF}$		4.7 6.2	7.3 9.3	1.0 1.0	8.5 10.5	
t _{PLZ} ,	Output Disable Time OEA to YA or OEB to YB	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $C_L = 50 \text{ pF}$		10.3	14.0	1.0	16.0	ns
t _{PHZ}	OEA to YA OF OEB to YB	$V_{CC} = 5.0 \pm 0.5 \text{ V}$ $C_L = 50 \text{ pF}$		6.7	9.2	1.0	10.5	
t _{OSLH} , t _{OSHL}	Output to Output Skew	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $C_L = 50 \text{ pF}$ (Note 6)			1.5		1.5	ns
		$V_{CC} = 5.0 \pm 0.5 \text{ V}$ $C_L = 50 \text{ pF}$ (Note 6)			1.0		1.0	
C _{in}	Maximum Input Capacitance			4	10		10	pF
C _{out}	Maximum Three-State Output Capacitance (Output in High- Impedance State)			6				pF

		Typical @ 25°C, V _{CC} = 5.0 V	
C _{PD}	Power Dissipation Capacitance (Note 7)	17	pF

NOISE CHARACTERISTICS (MC74VHC240) ($C_L = 50 \text{ pF}, V_{CC} = 5.0 \text{ V}$)

		T _A = 25°C		
Symbol	Parameter	Тур	Max	Unit
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	0.6	0.9	V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	-0.6	-0.9	V
V _{IHD}	Minimum High Level Dynamic Input Voltage		3.5	V
V _{ILD}	Maximum Low Level Dynamic Input Voltage		1.5	V

Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.
 C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/8 (per bit). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

DC ELECTRICAL CHARACTERISTICS (MC74VHCT240A)

			V _{CC}	Т	A = 25°	С	T _A = - 40 to 85°C		
Symbol	Parameter	Test Conditions	v	Min	Тур	Max	Min	Max	Unit
V _{IH}	Minimum High-Level Input Voltage		4.5 to 5.5	2.0			2.0		V
V _{IL}	Maximum Low-Level Input Voltage		4.5 to 5.5			0.8		0.8	٧
V _{OH}	Minimum High-Level Output	I _{OH} = - 50 μA	4.5	4.4	4.5		4.4		V
	Voltage $V_{in} = V_{IH}$ or V_{IL}	I _{OH} = – 8 mA	4.5	3.94			3.80		
V _{OL}	Maximum Low-Level Output	I _{OL} = 50 μA	4.5		0.0	0.1		0.1	V
	Voltage $V_{in} = V_{IH}$ or V_{IL}	I _{OL} = 8 mA	4.5			0.36		0.44	
I _{in}	Maximum Input Leakage Current	V _{in} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
l _{OZ}	Maximum 3-State Leakage Current	$V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$	5.5			±0.25		±2.5	μΑ
Icc	Maximum Quiescent Supply Current	V _{in} = V _{CC} or GND	5.5			4.0		40.0	μΑ
I _{CCT}	Quiescent Supply Current	Per Input: V _{IN} = 3.4 V Other Input: V _{CC} or GND	5.5			1.35		1.50	mA
I _{OPD}	Output Leakage Current	V _{OUT} = 5.5 V	0			0.5		5.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (MC74VHCT240A)

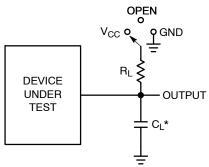
			T _A = 25°C		T _A = - 40) to 85°C			
Symbol	Parameter	Test Condit	ions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Maximum Propagation Delay A to YA or B to YB	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	$C_L = 15 pF$ $C_L = 50 pF$		5.6 6.1	7.8 8.8	1.0 1.0	9.0 10.0	ns
t _{PZL} , t _{PZH}	Output Enable Time OEA to YA or OEB to YB	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	$C_L = 15p F$ $C_L = 50 pF$		7.7 8.2	10.4 11.4	1.0 1.0	12.0 13.0	ns
t _{PLZ} , t _{PHZ}	Output Disable Time OEA to YA or OEB to YB	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C _L = 50 pF		8.8	11.4	1.0	13.0	ns
t _{OSLH} , t _{OSHL}	Output to Output Skew	V _{CC} = 5.0 ± 0.5 V (Note 8)	C _L = 50 pF			1.0		1.0	ns
C _{in}	Maximum Input Capacitance				4	10		10	pF
C _{out}	Maximum Three–State Output Ca- pacitance (Output in High–Imped- ance State)				9				pF

		Typical @ 25°C, V _{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Note 9)	19	pF

NOISE CHARACTERISTICS (MC74VHCT240A) ($C_L = 50 \text{ pF}, V_{CC} = 5.0 \text{ V}$)

		T _A = 25°C		
Symbol	Parameter	Тур	Max	Unit
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	0.9	1.1	V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	-0.9	-1.1	V
V _{IHD}	Minimum High Level Dynamic Input Voltage		2.0	V
V _{ILD}	Maximum Low Level Dynamic Input Voltage		0.8	V

Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.
 C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/8 (per bit). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

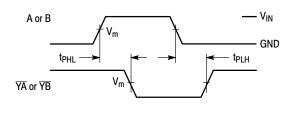


 $^{\star}C_L$ Includes probe and jig capacitance Input signal t_R = t_F = 3 ns

Test	Switch Position	C _L	R _L
t _{PLH} / t _{PHL}	Open	See AC Characteristics	1 kΩ
t _{PLZ} / t _{PZL}	V _{CC}	Table	
t _{PHZ} / t _{PZH}	GND		

Figure 2. Test Circuits

SWITCHING WAVEFORMS



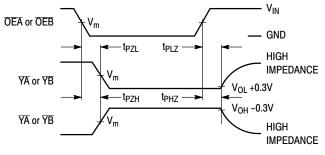


Figure 3.

Figure 4.

Device	V _{IN} , V	V _m , V
MC74VHC240	V _{CC}	50% x V _{CC}
MC74VHCT240A	3 V	1.5 V

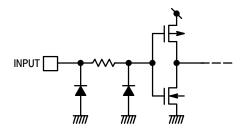


Figure 5. Input Equivalent Circuit

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74VHC240DWR2G	VHC240G	SOIC-20W	1000 / Tape & Reel
MC74VHC240DTR2G	VHC 240	TSSOP-20	2500 / Tape & Reel
MC74VHCT240ADWR2G	VHCT240AG	SOIC-20W	1000 / Tape & Reel
MC74VHCT240ADTR2G	VHCT 240A	TSSOP-20	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

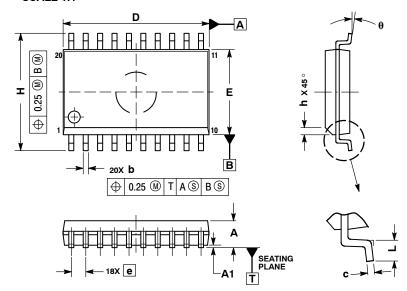




SOIC-20 WB CASE 751D-05 **ISSUE H**

DATE 22 APR 2015

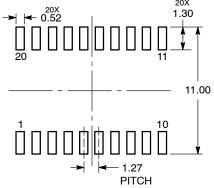
SCALE 1:1



- DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

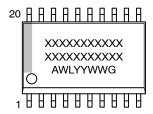
	MILLIMETERS		
DIM	MIN	MAX	
Α	2.35	2.65	
A1	0.10	0.25	
b	0.35	0.49	
С	0.23	0.32	
D	12.65	12.95	
E	7.40	7.60	
е	1.27 BSC		
Н	10.05	10.55	
h	0.25	0.75	
L	0.50	0.90	
A	0 °	7 °	

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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